

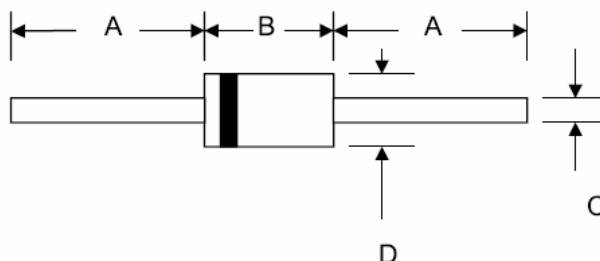


**Technical Data**

*Green Products*

**Data Sheet N0544, Rev. -  
Features**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



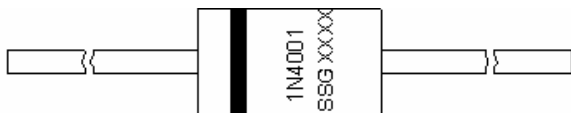
**Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.35 grams (approx.)
- Mounting Position: Any
- Marking: Part Name,SSG and Date Code

DO-41				
Dim	Min	Max	Min	Max
A	25.4	—	1.000	—
B	4.06	5.21	0.159	0.205
C	0.71	0.864	0.028	0.034
D	2.00	2.72	0.079	0.107
	In mm		In inch	

**Marking Diagram:**

Where XXXXX is YYWWL



- 1N4001 = Part Name
- SSG = SSG
- YY = Year
- WW = Week
- L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

**Ordering Information**

Device	Package	Shipping
1N4001G-1N4007G	DO-41 (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



**Maximum Ratings and Electrical Characteristics** @ $T_A=25^\circ\text{C}$  unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	1N 4001G	1N 4002G	1N 4003G	1N 4004G	1N 4005G	1N 4006G	1N 4007G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @ $T_A = 75^\circ\text{C}$	$I_o$	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	30							A
Forward Voltage @ $I_F = 1.0\text{A}$	$V_{FM}$	1.0							V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_{RM}$	5.0 50							$\mu\text{A}$
Typical Junction Capacitance (Note 2)	$C_j$	8.0							pF
Typical Thermal Resistance Junction to Ambient (Note 1)	$R_{\theta JA}$	100							K/W
Operating Temperature Range	$T_j$	-65 to +175							$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-65 to +175							$^\circ\text{C}$

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case  
2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.



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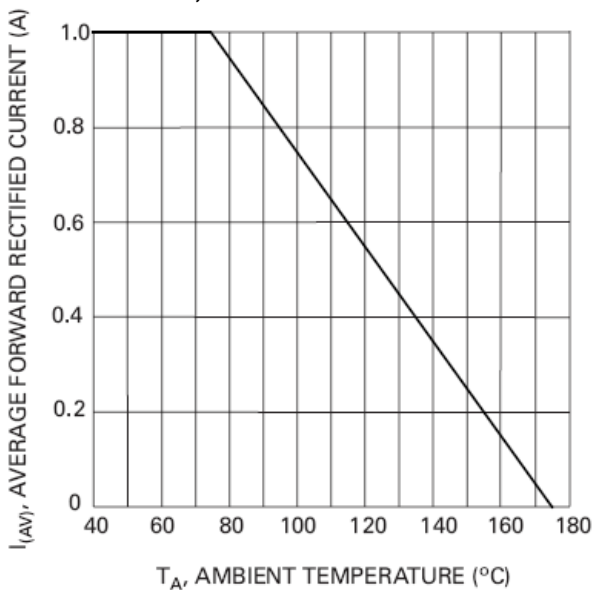


Fig. 1 Forward Current Derating Curve

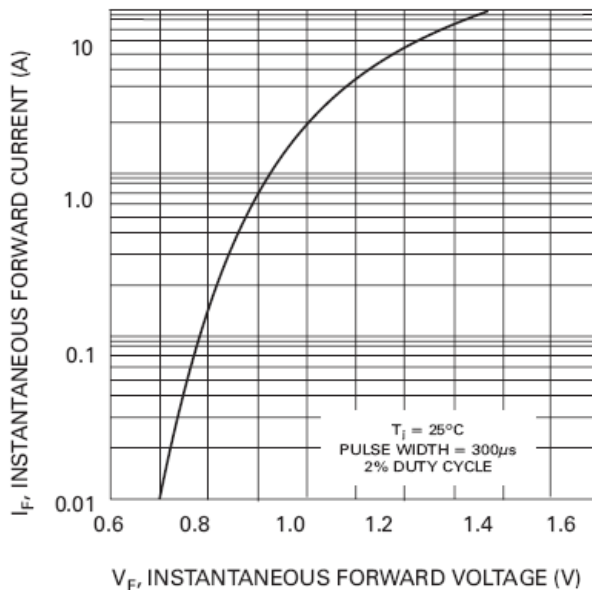


Fig. 2 Typical Forward Characteristics

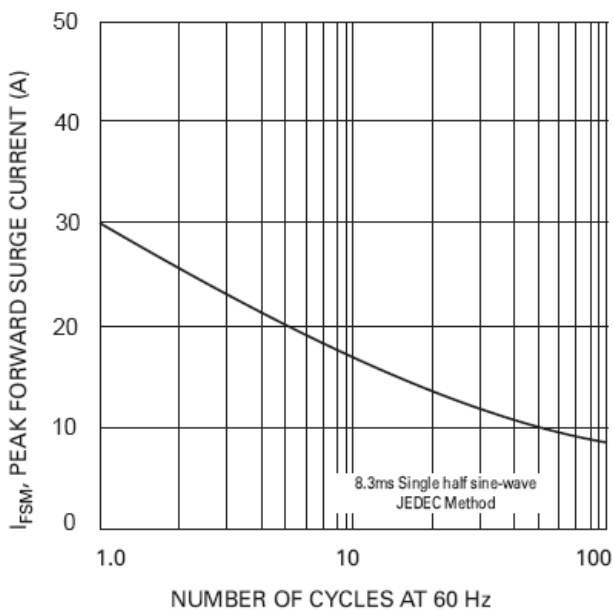


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

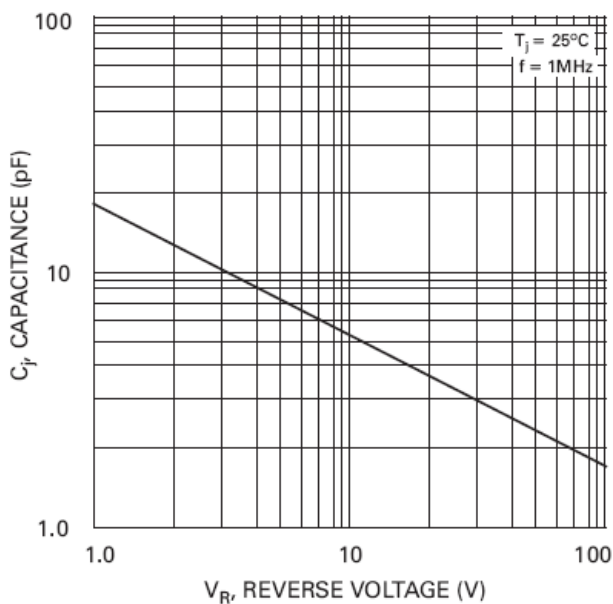


Fig. 4 Typical Junction Capacitance



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